

## HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

- VERY LOW CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIMES
- HIGH SURGE CURRENT
- THE SPECIFICATIONS AND CURVES ENABLE THE DETERMINATION OF  $t_{rr}$  AND  $I_{RM}$  AT 100°C UNDER USERS CONDITIONS

### DESCRIPTION

Low voltage drop rectifiers suited for switching mode base drive and transistor circuits.



**DO 27A**  
(Plastic)

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$I_{FRM}$	Repetitive Peak Forward Current	70	A
$I_F$ (AV)	Average Forward Current*	3	A
$I_{FSM}$	Surge non Repetitive Forward Current	70	A
$P_{tot}$	Power Dissipation*	2.5	W
$T_{stg}$ $T_j$	Storage and Junction Temperature Range	- 40 to 150	°C
$T_L$	Maximum Lead Temperature for Soldering during 10s at 4mm from Case	230	°C

Symbol	Parameter	BYW 98-				Unit
		50	100	150	200	
$V_{RRM}$	Repetitive Peak Reverse Voltage	50	100	150	200	V
$V_{RSM}$	Non Repetitive Peak Reverse Voltage	55	110	165	220	V

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction-ambient*	25	°C/W

\* On infinite heatsink with 10mm lead length

**ELECTRICAL CHARACTERISTICS****STATIC CHARACTERISTICS**

<b>Symbol</b>	<b>Test Conditions</b>		<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
$I_R$	$T_j = 25^\circ C$	$V_R = V_{RRM}$			10	$\mu A$
	$T_j = 100^\circ C$				0.5	$mA$
$V_F$	$T_j = 25^\circ C$	$I_F = 9A$			1.1	$V$
	$T_j = 100^\circ C$	$I_F = 3A$			0.85	

**RECOVERY CHARACTERISTICS**

<b>Symbol</b>	<b>Test Conditions</b>			<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
$t_{rr}$	$T_j = 25^\circ C$ $V_R = 30V$	$I_F = 1A$ See figure 10	$di_F/dt = - 50A/\mu s$			35	ns
$Q_{rr}$	$T_j = 25^\circ C$ $V_R \leq 30V$	$I_F = 2A$	$di_F/dt = - 20A/\mu s$		12		nC
$t_{fr}$	$T_j = 25^\circ C$ Measured at $1.1 \times V_F$	$I_F = 1A$	$t_r = 10ns$		20		ns
$V_{FP}$	$T_j = 25^\circ C$	$I_F = 1A$	$t_r = 10ns$		5		V

To evaluate the conduction losses use the following equations :

$$V_F = 0.66 + 0.03 I_F$$

$$P = 0.06 \times I_F(AV) + 0.03 I_F^2(RMS)$$

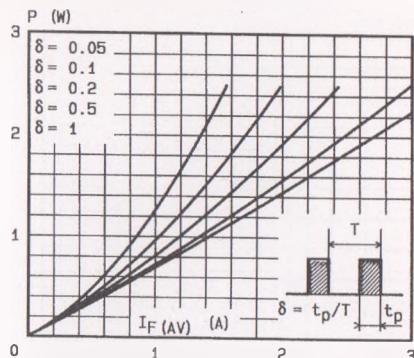


Fig.1 - Maximum average power dissipation versus average forward current.

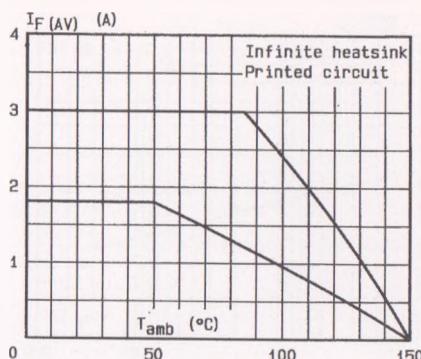


Fig.2 - Average forward current versus ambient temperature.

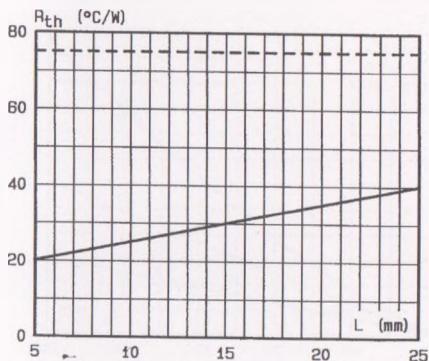


Fig.3 - Thermal resistance versus lead length.

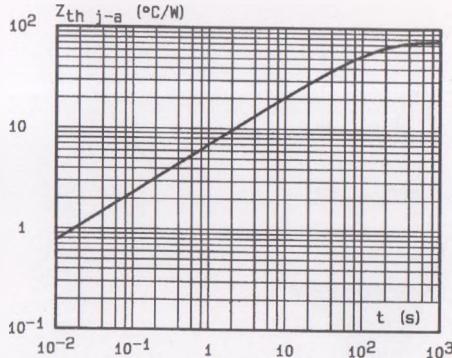


Fig.4 - Transient thermal impedance junction-ambient for mounting n°2 versus pulse duration ( $L = 10$  mm).

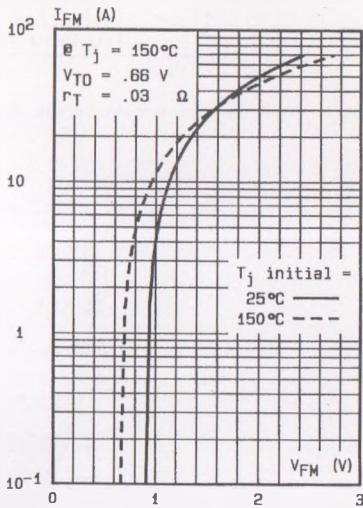
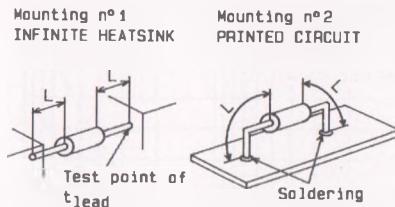


Fig.5 - Peak forward current versus peak forward voltage drop (maximum values).

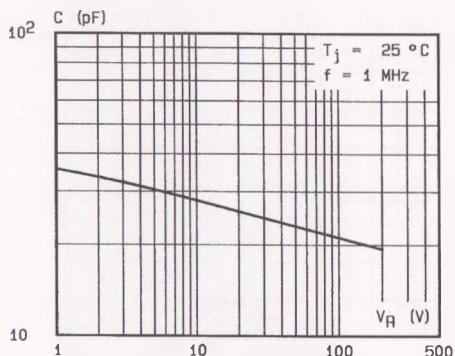


Fig.6 - Capacitance versus reverse voltage applied.

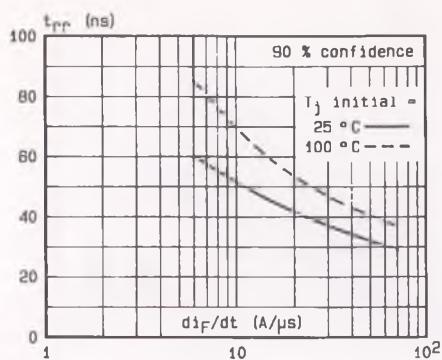


Fig.7 - Recovery time versus  $dI/dt$ .

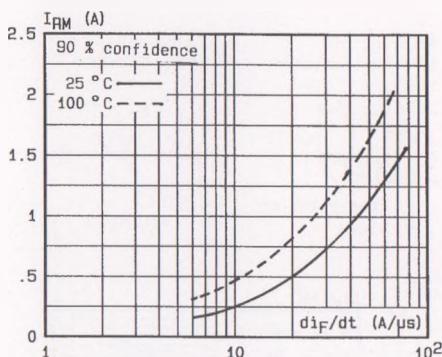


Fig.8 - Peak reverse current versus  $dI/dt$ .

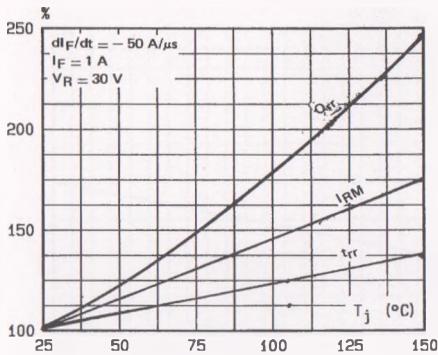


Fig.9 - Dynamic parameters versus junction temperature.

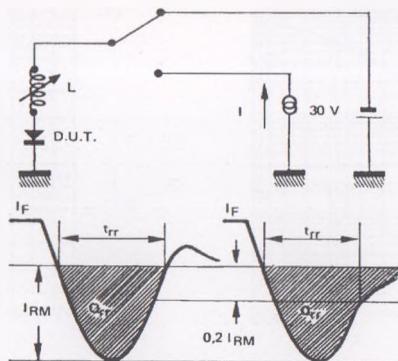


Fig.10 - Measurement of  $t_{rr}$  (Fig.7) and  $I_{RM}$  (Fig.8).